

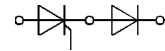
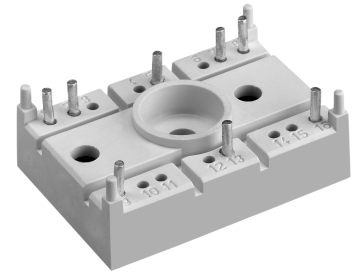
$V_{RSM}$	$V_{RRM}$	$I_{TAV}$ (maximum values for cont. operation) ( $T_h = 85\text{ °C}$ ) 45 A
V	$V_{DRM}$	
1300	1200	<b>SK 60 KL 12 F<sup>1)</sup></b>

### SEMITOP® 2

### Thyristor/Diode Module

### SK 60 KL 12 F<sup>1)</sup>

Symbol	Conditions	Values	Units
$I_{TAV}/I_{FAV}$	sin. 180°; $T_h = 80\text{ °C}$ $T_h = 85\text{ °C}$	65 / 47 60 / 45	A A
$T_{stg}$		- 40 ... +125	°C
$T_{solder}$	terminals, 10 s	260	°C
$I_{TSM}/I_{FSM}$	$T_{vj} = 25\text{ °C}$ ; 10 ms $T_{vj} = 125\text{ °C}$ ; 10 ms	- 1800 / 800	A A
$i^2t$	$T_{vj} = 25\text{ °C}$ ; 8,3 ... 10 ms $T_{vj} = 125\text{ °C}$ ; 8,3 ... 10 ms	- 3160	A <sup>2</sup> s A <sup>2</sup> s
<b>Thyristor</b>			
$t_{gd}$	$T_{vj} = 25\text{ °C}$ ; $I_G = 1\text{ A}$ ; $di_G / dt = 1\text{ A} / \mu\text{s}$	1	$\mu\text{s}$
$t_{gr}$	$V_D = 0,67 V_{DRM}$	2	$\mu\text{s}$
$(dv/dt)_{cr}$	$T_{vj} = 125\text{ °C}$	1000	V/ $\mu\text{s}$
$(di/dt)_{cr}$	$T_{vj} = 125\text{ °C}$ ; $f = 50 \dots 60\text{ Hz}$	50	A/ $\mu\text{s}$
$t_q$	$T_{vj} = 125\text{ °C}$ ; typ.	80	$\mu\text{s}$
$I_H$	$T_{vj} = 25\text{ °C}$ ; typ. / max.	100 / 200	mA
$I_L$	$T_{vj} = 25\text{ °C}$ ; $R_G = 33\ \Omega$ ; typ. / max.	200 / 500	mA
$V_T$	$T_{vj} = 25\text{ °C}$ ; ( $I_T = 300\text{ A}$ ); max.	1,85	V
$V_{T(T0)}$	$T_{vj} = 125\text{ °C}$	0,9	V
$r_T$	$T_{vj} = 125\text{ °C}$	3,5	m $\Omega$
$I_{DD}$ ; $I_{RD}$	$T_{vj} = 125\text{ °C}$ ; $V_{DD} = V_{DRM}$ ; $V_{RD} = V_{RRM}$	20	mA
$V_{GT}$	$T_{vj} = 25\text{ °C}$ ; dc	2	V
$I_{GT}$	$T_{vj} = 25\text{ °C}$ ; dc	100	mA
$V_{GD}$	$T_{vj} = 125\text{ °C}$ ; dc	0,25	V
$I_{GD}$	$T_{vj} = 125\text{ °C}$ ; dc	5	mA
$R_{thjh}^{2)}$	cont. / sin. 180° p. thyristor	0,45 / 0,47	K/W
$T_{vj}$		- 40 ... + 125	°C
<b>Diode</b>			
$V_F$	$T_{vj} = 25\text{ °C}$ ; ( $I_F = 100\text{ A}$ ); max.	2,5	V
$V_{(T0)}$	$T_{vj} = 125\text{ °C}$	1,2	V
$r_T$	$T_{vj} = 125\text{ °C}$	11	m $\Omega$
$I_R$	$T_{vj} = 150\text{ °C}$ ; $V_{RD} = V_{RRM}$	8	mA
$R_{thjh}^{2)}$		0,6	K/W
$T_{vj}$		- 40 ... + 150	°C
<b>Mechanical Data</b>			
$V_{isol}$	a.c. 50 Hz; r.m.s.; 1 s / 1 min	3000 / 2500	V
$M_1$	mounting torque	2	Nm
$W$		19	g
<b>Case</b>		T 29	



KL

#### Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Glass passivated thyristor chips
- High surge currents
- Fast & soft CAL-diode<sup>1)</sup>
- UL recognized, file no. E 63 532

#### Typical Applications

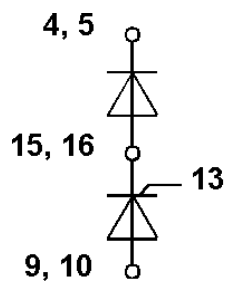
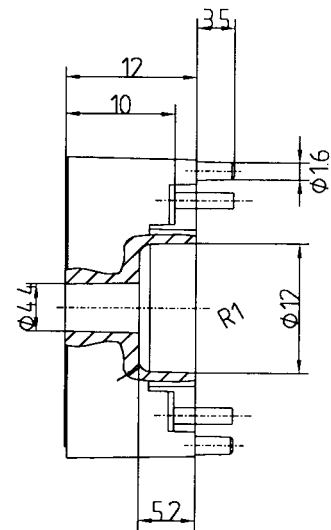
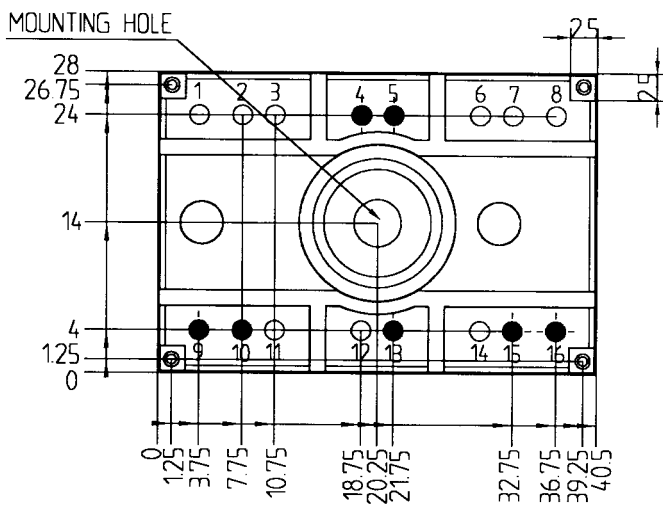
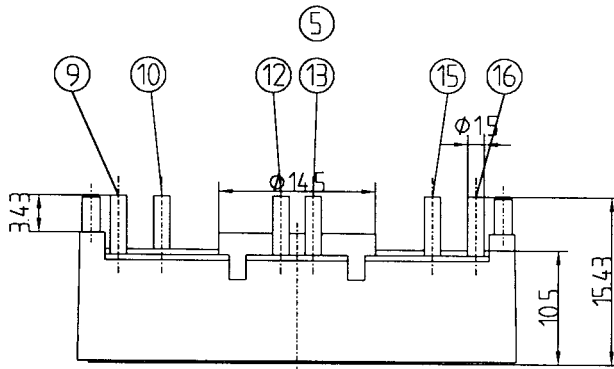
- UPS

<sup>1)</sup> CAL (Controlled axial lifetime) technology

<sup>2)</sup> Thermal resistance junction to heatsink

SEMITOP® 2  
SK 60 KL 12 F

Case T 29



Dimensions in mm